NSN 5962-01-111-7478

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-111-7478 **Features Provided:** Monolithic and programmable and 3-state output **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 9 input **Terminal Surface Treatment:** Solder **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:**

05869-726009-1 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing) Terminal Type And Quantity:

16 printed circuit

To printed ende

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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